UNISONIC TECHNOLOGIES CO., LTD

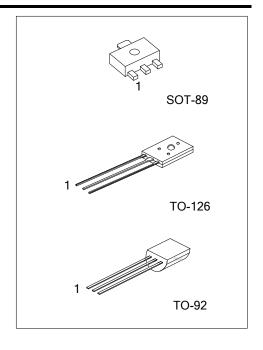
2N5401

PNP SILICON TRANSISTOR

HIGH VOLTAGE SWITCHING **TRANSISTOR**

FEATURES

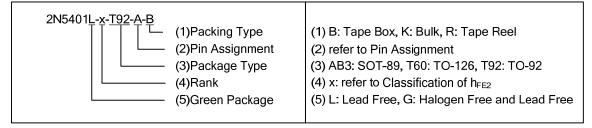
- * Collector-emitter voltage: $V_{CEO} = -150V$
- * High current gain,



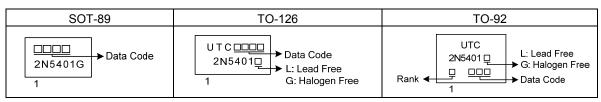
ORDERING INFORMATION

Ordering Number		Dookogo	Pin Assignment			Dooking	
Lead Free	Halogen Free	Package	1	2	3	Packing	
-	2N5401G-x-AB3-R	SOT-89	В	C	Е	Tape Reel	
2N5401L-T60-K	2N5401G-T60-K	TO-126	Е	C	В	Bulk	
2N5401L-x-T92-B	2N5401G-x-T92-B	TO-92	Е	В	С	Tape Box	
2N5401L-x-T92-K	2N5401G-x-T92-K	TO-92	Е	В	С	Bulk	
2N5401L-x-T92-A-B	2N5401G-x-T92-A-B	TO-92	E	С	В	Tape Box	
2N5401L-x-T92-A-K	2N5401G-x-T92-A-K	TO-92	E	C	В	Bulk	

Note: Pin Assignment: B: Base C: Collector E: Emitter



MARKING



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■ ABSOLUTE MAXIMUM RATING (T_A=25°C, unless otherwise specified)

PARAMETER		SYMBOL	RATINGS	UNIT
Collector-Base Voltage		V_{CBO}	-160	V
Collector-Emitter Voltage		V_{CEO}	-150	V
Emitter-Base Voltage		V_{EBO}	-5	V
Collector Current		Ic	-600	mA
Collector Dissipation	SOT-89		500	mW
	TO-126	Pc	1500	mW
	TO-92		625	mW
Junction Temperature		TJ	+150	°C
Storage Temperature		T _{STG}	-55 ~ +150	°C

Note: Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

■ **ELECTRICAL CHARACTERISTICS** (T_A=25°C, unless otherwise specified)

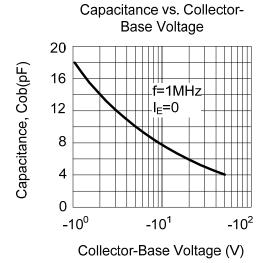
PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Collector-Base Breakdown Voltage	BV_CBO	$I_C = -100 \mu A, I_E = 0$	-160			V
Collector-Emitter Breakdown Voltage	BV_CEO	$I_{C} = -1 \text{mA}, I_{B} = 0$	-150			V
Emitter-Base Breakdown Voltage	BV_{EBO}	$I_E = -10\mu A, I_C = 0$	-5			V
Collector Cut-off Current	I _{CBO}	$V_{CB} = -120V, I_E = 0$			-50	nA
Emitter Cut-off Current	I _{EBO}	$V_{EB} = -3V, I_{C} = 0$			-50	nA
DC Current Gain (Note)	h _{FE1}	$V_{CE} = -5V$, $I_C = -1mA$	80			
	h _{FE2}	$V_{CE} = -5V, I_{C} = -10mA$	80		400	
	h _{FE3}	$V_{CE} = -5V, I_{C} = -50mA$	80			
Collector Emitter Saturation Voltage	V _{CE(SAT)}	$I_{\rm C} = -10 \rm mA, \ I_{\rm B} = -1 \rm mA$			-0.2	V
Collector-Emitter Saturation Voltage		$I_{\rm C}$ = -50mA, $I_{\rm B}$ = -5mA			-0.5	V
Door Emitter Cotumption Voltage	VRE(SAT)	$I_{\rm C} = -10 \rm mA, \ I_{\rm B} = -1 \rm mA$			-1	V
Base-Emitter Saturation Voltage		$I_{\rm C}$ = -50mA, $I_{\rm B}$ = -5mA			-1	V
Current Gain Bandwidth Product	f _T	$V_{CE} = -10V, I_{C} = -10mA$ f = 100MHz	100		400	MHz
Output Capacitance	Сов	$V_{CB} = -10V$, $I_E = 0$, $f = 1MHz$			6.0	pF
Noise Figure	NF	I_C = -0.25mA, V_{CE} = -5V R _S = 1k Ω , f = 10Hz ~ 15.7kHz			8	dB

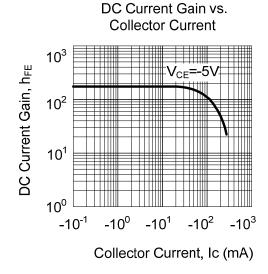
Note: Pulse test: P_W < 300 μ s, Duty Cycle < 2%.

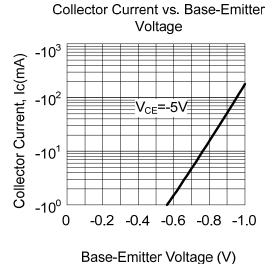
■ CLASSIFICATION OF h_{FE2}

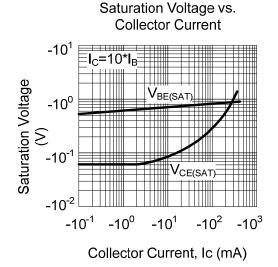
RANK	А	В	С
RANGE	80-170	150-240	200-400

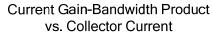
■ TYPICAL CHARACTERISTICS

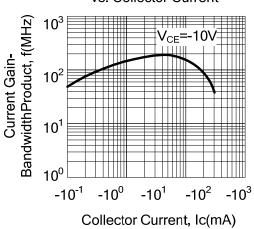


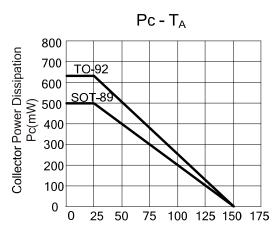












Ambient Temperature (°C)

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